

英飞凌之低电压功率晶体管技术

低电压功率晶体管结构

晶粒技术发展

封装技术发展

双层冷却封装之功率晶体管 – CanPAK

英飞凌之低电压功率晶体管

总结

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电源产品 设计需求

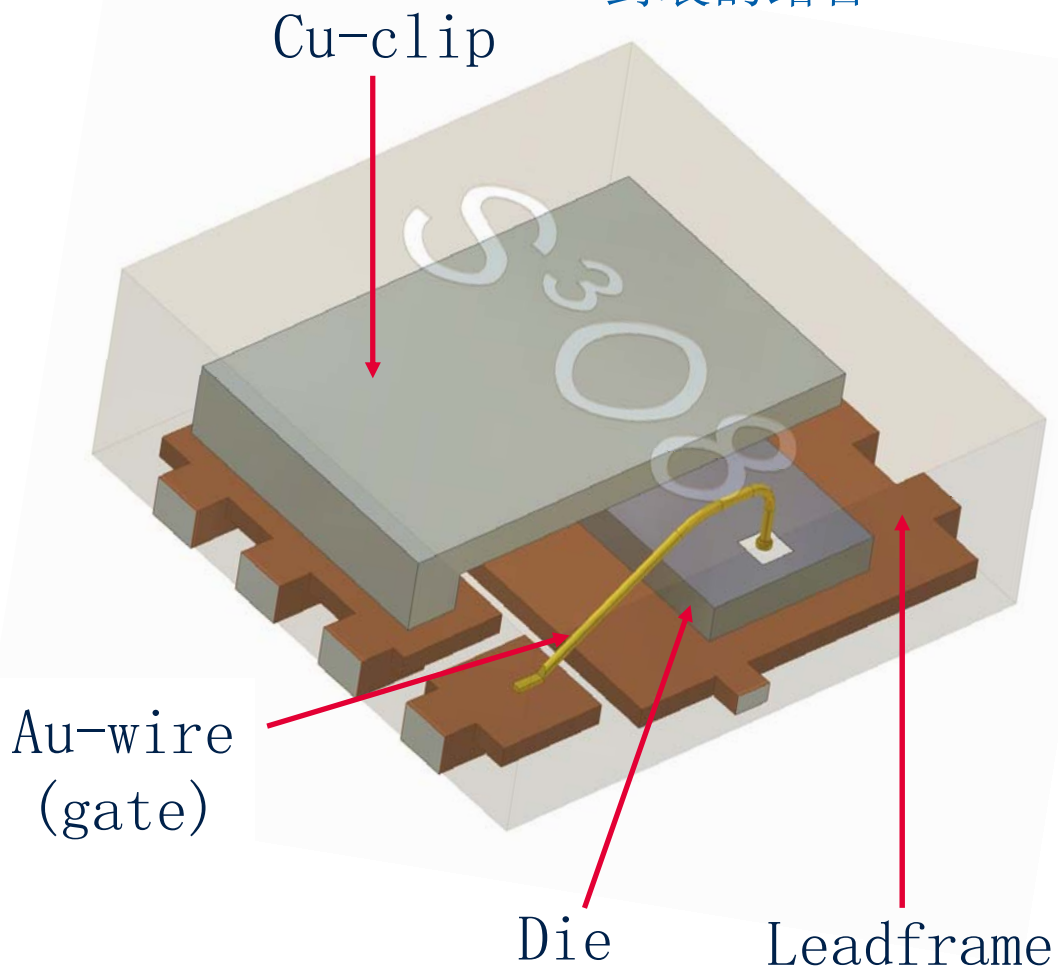
- 高功率密度
- 高转换效率
- 较佳的效能/成本比



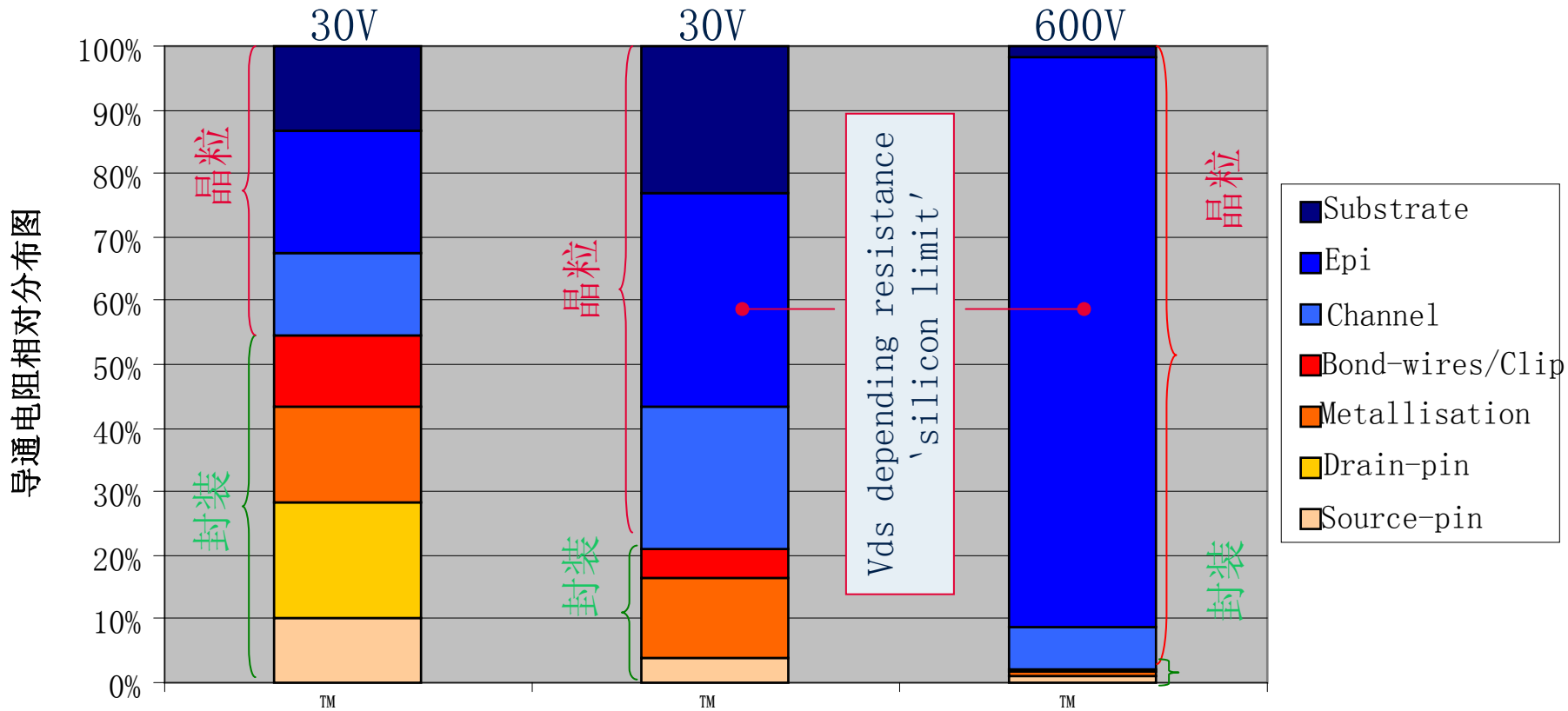
晶粒技术

封装技术

功率晶体管的参数值呈现来自晶粒及封装的结合



晶体管导通电阻分布图



- 在低电压功率晶体管中，封装电阻在整体导通电阻中所占比例较大
- 在高电压功率晶体管中，晶粒导通电阻在整体导通电阻中所占比例较大
- 其中晶粒导通电阻中之Epi层电阻正比于 $V_{ds}^{2.5}$ (silicon limit)

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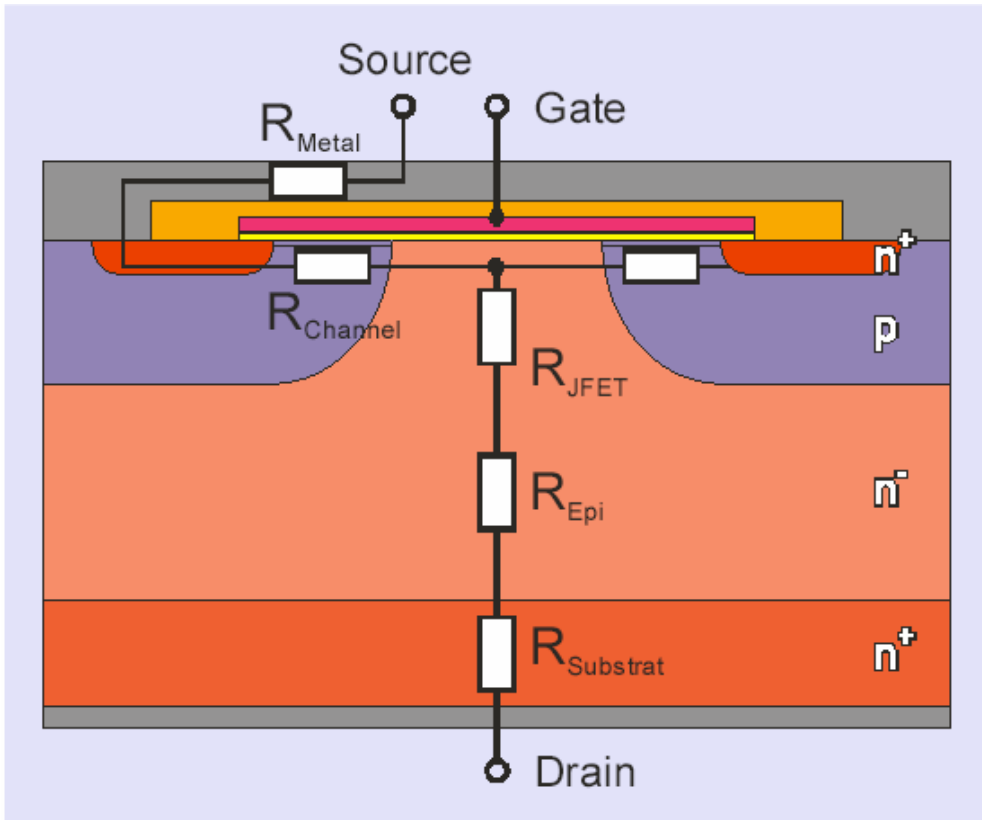
双层冷却封装之功率晶体管 – CanPAK

英飞凌之低电压功率晶体管

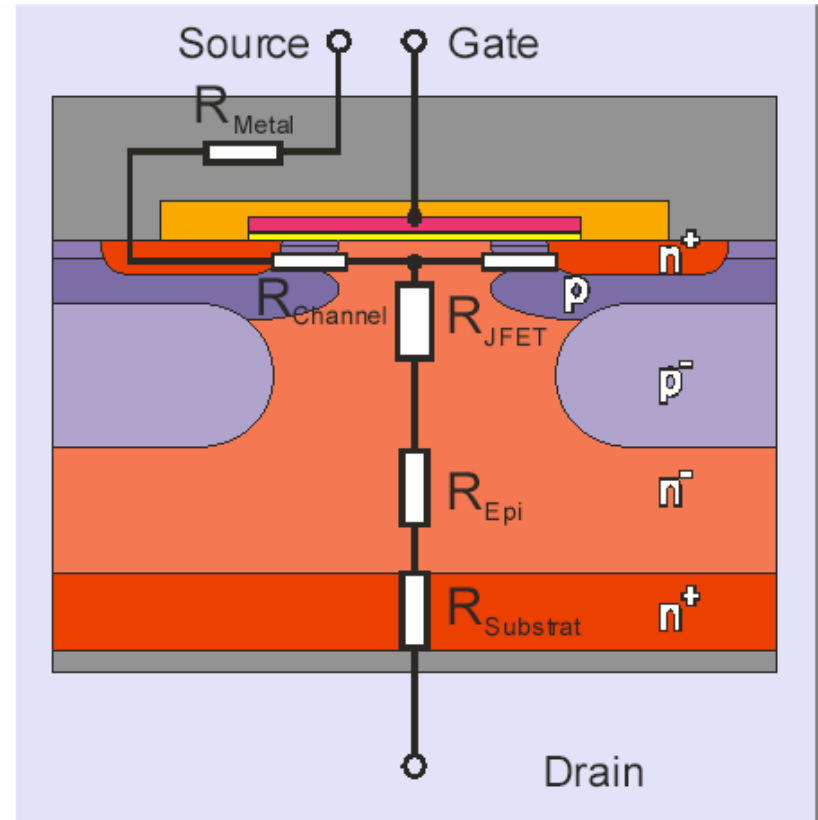
总结

低电压功率晶体管发展演进

标准平面 (Planar) 扩散型功率晶体管



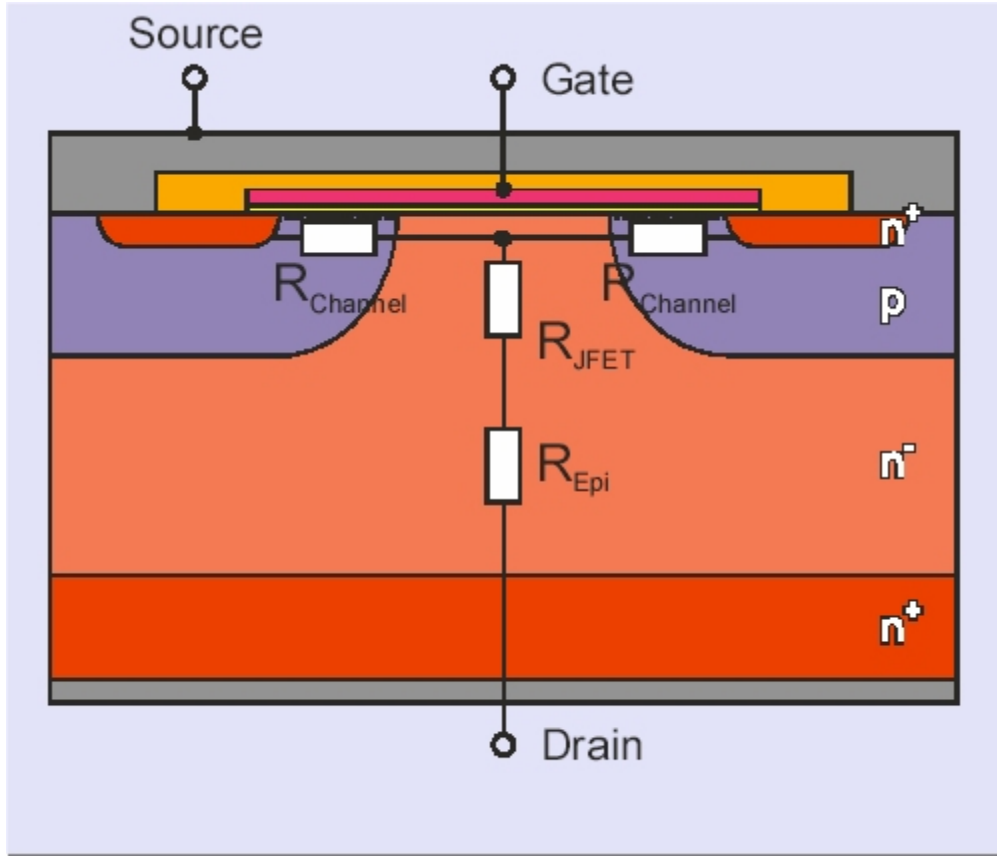
改良平面扩散型功率晶体管



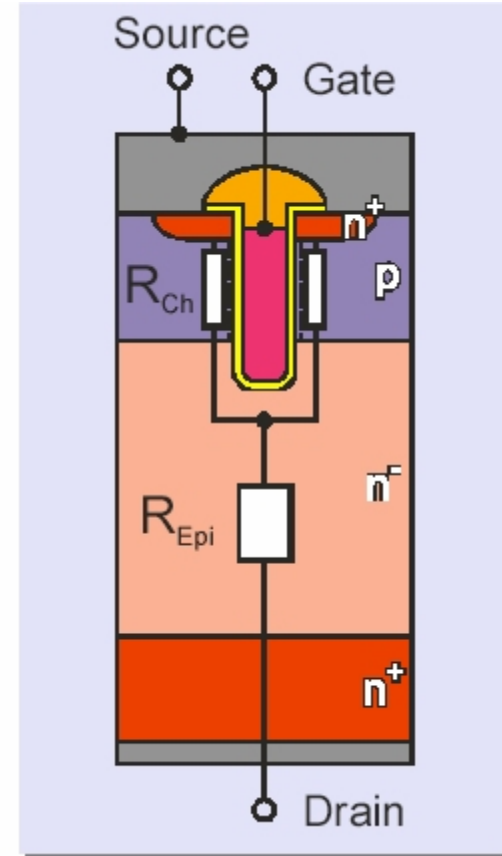
- 改善
- $R_{Channel}$
 - R_{JFET}
 - R_{Epi}

低电压功率晶体管发展演进 - II

平面扩散型

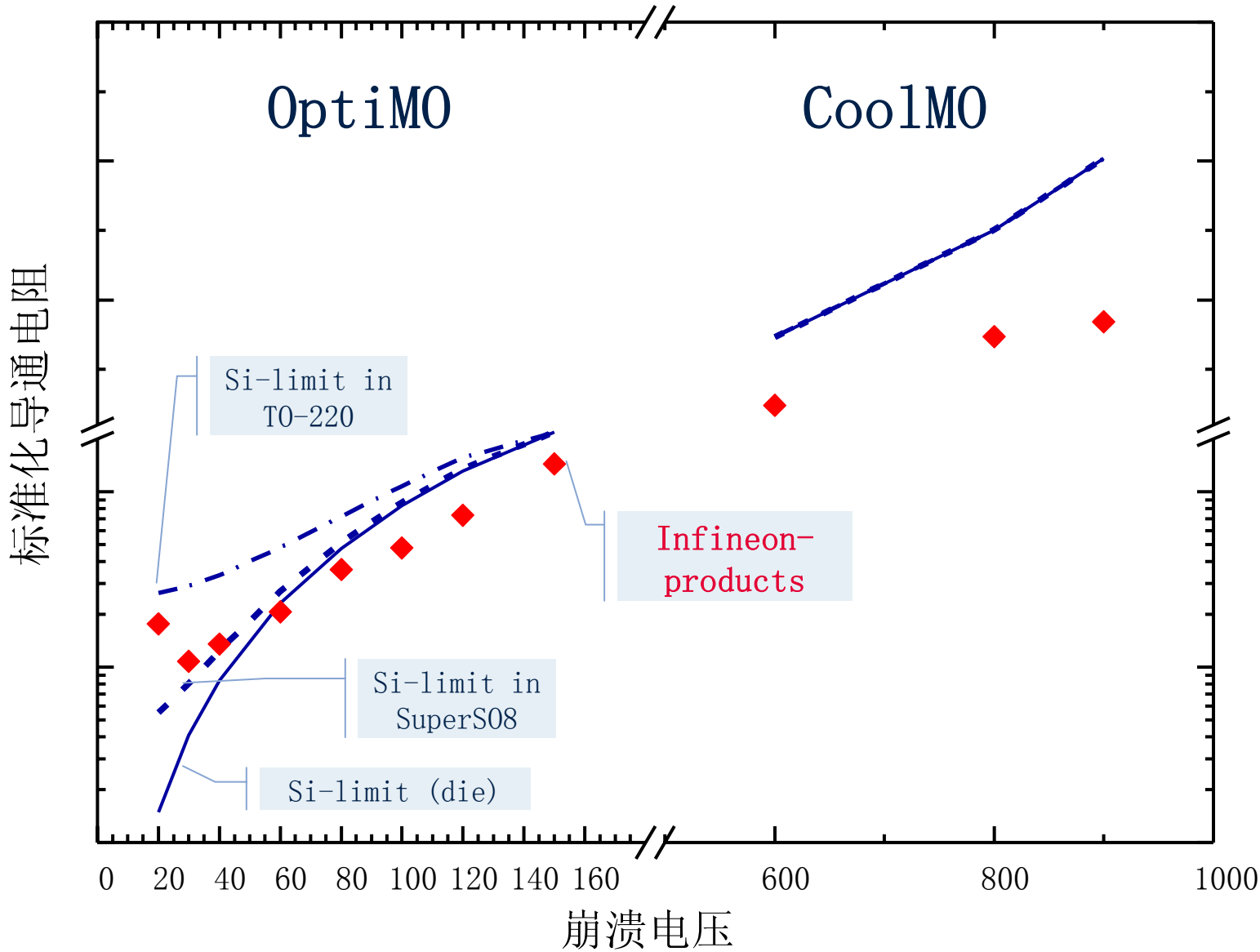


标准沟槽式 (Trench)



消除 RJFE
改进

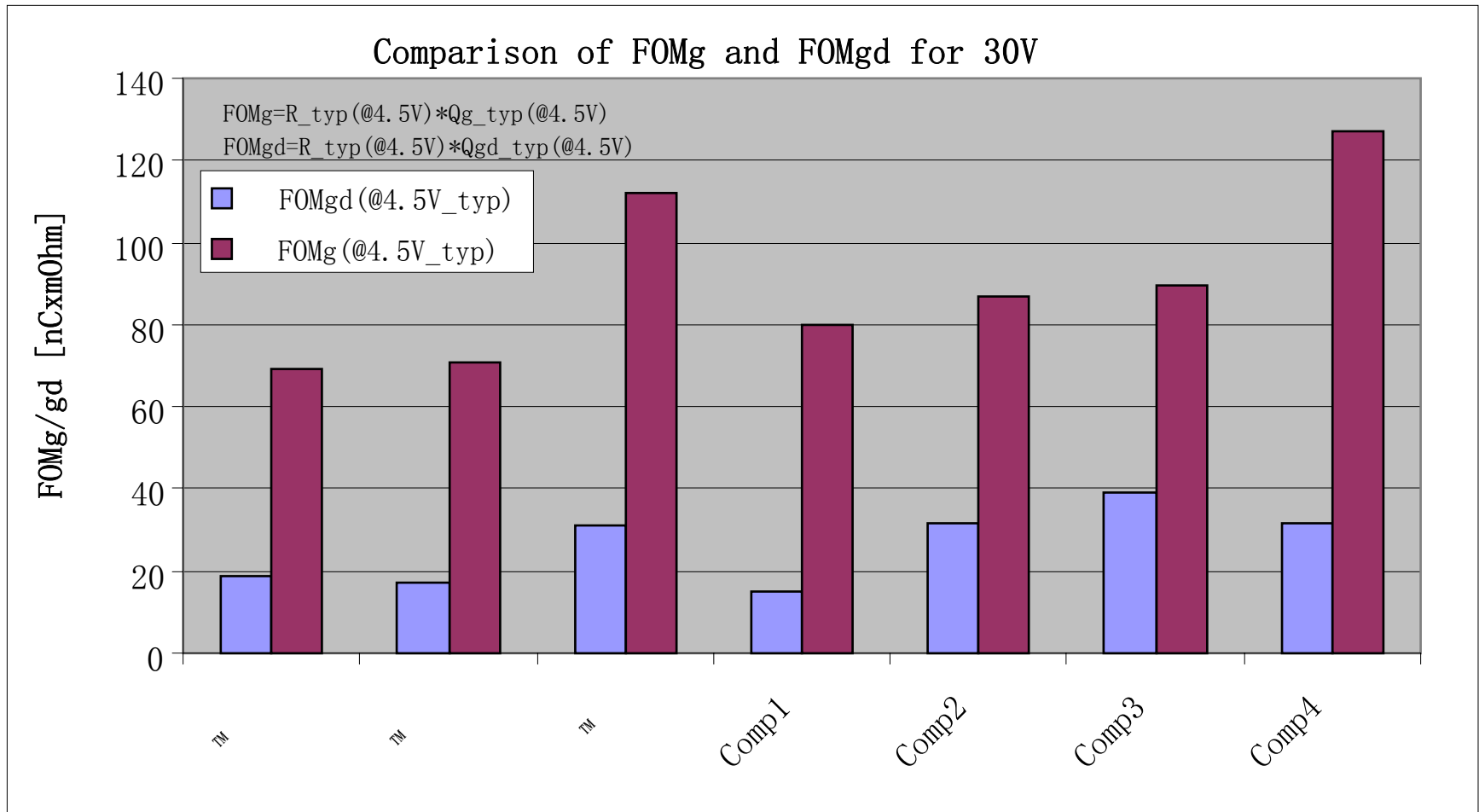
硅限制 (Si-limit) 及英飞凌之功率晶体管



30V功率晶体管之优质化系数比较图

优质化系数 Figure-Of-Merit $(FOMg) = Qg \times RDSon$

$(FOMgd) = Qgd \times RDSon$



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无引线功率晶体管封装

Leadless



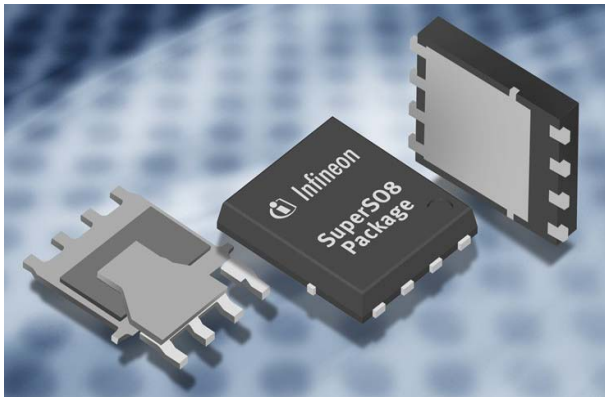
SuperSO8



Shrink Super SO8

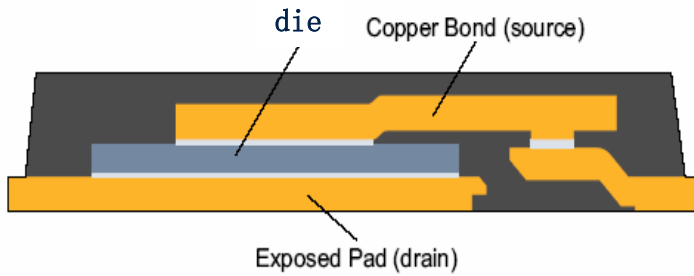


CanPAK

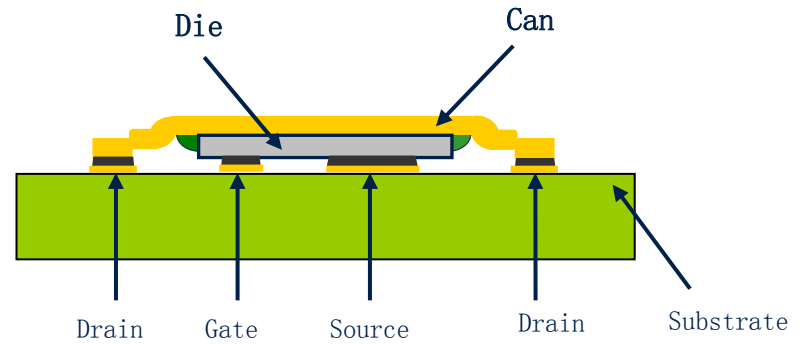


封装技术概述

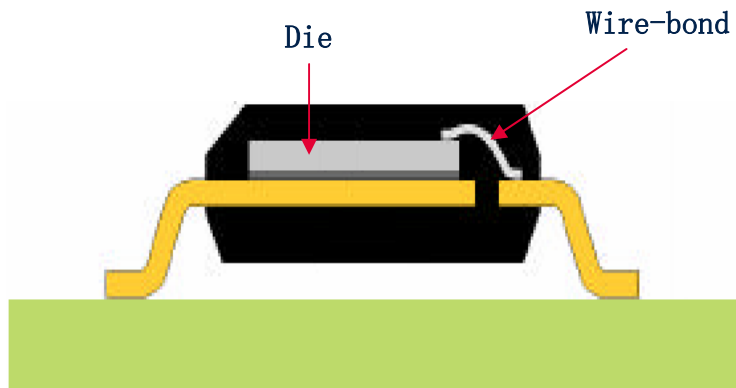
SuperS08



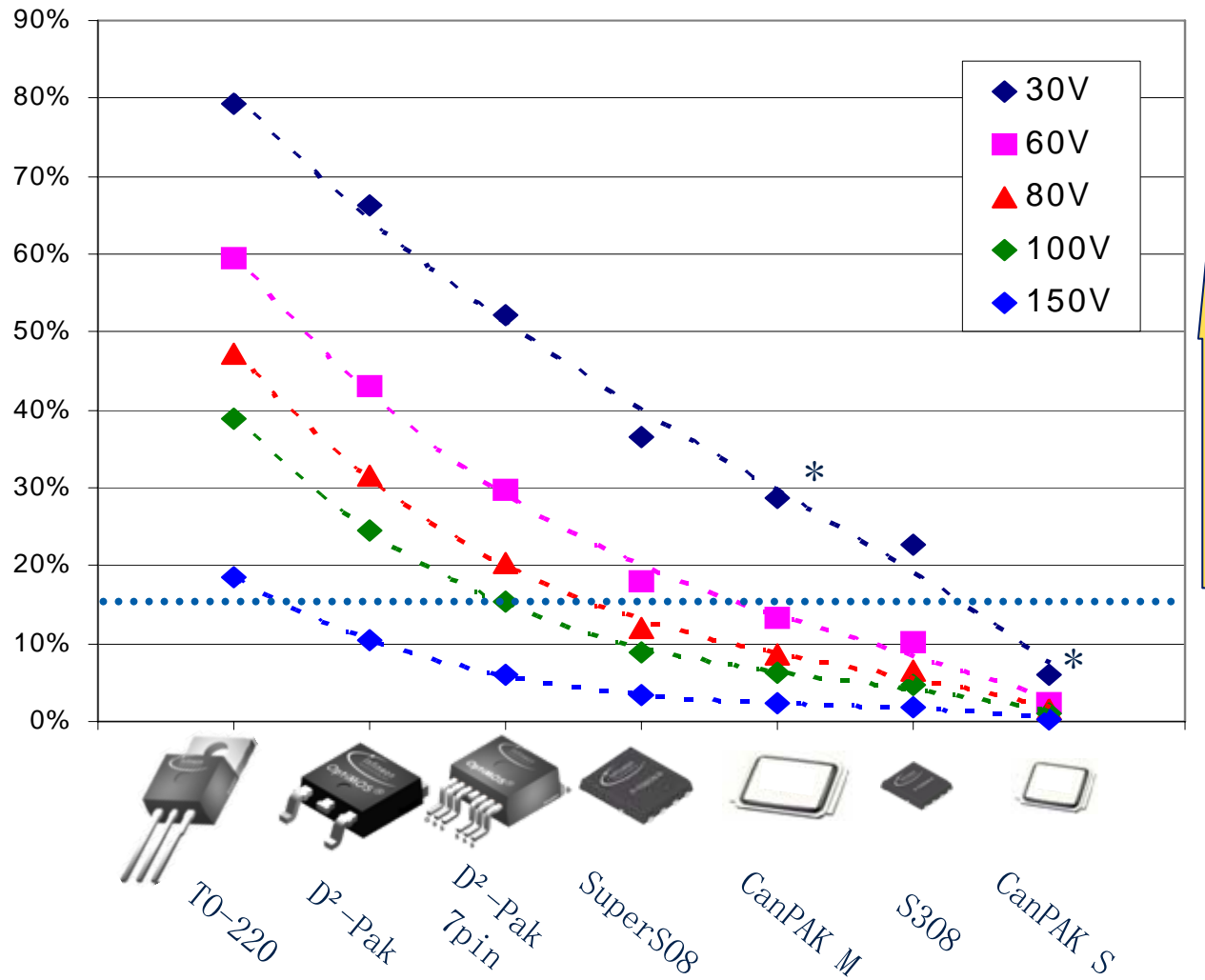
CanPAK



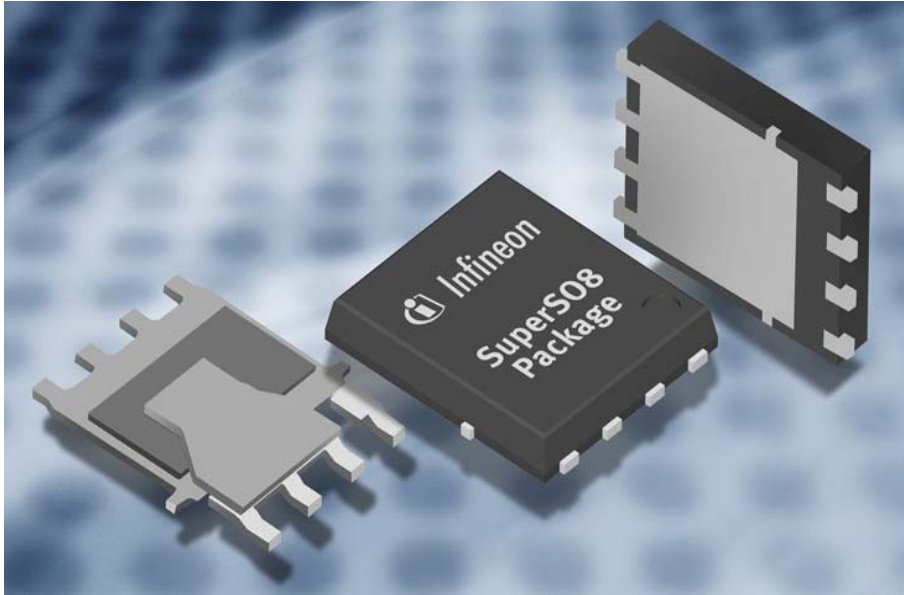
S08



封装寄生电阻对总导通电阻之贡献度

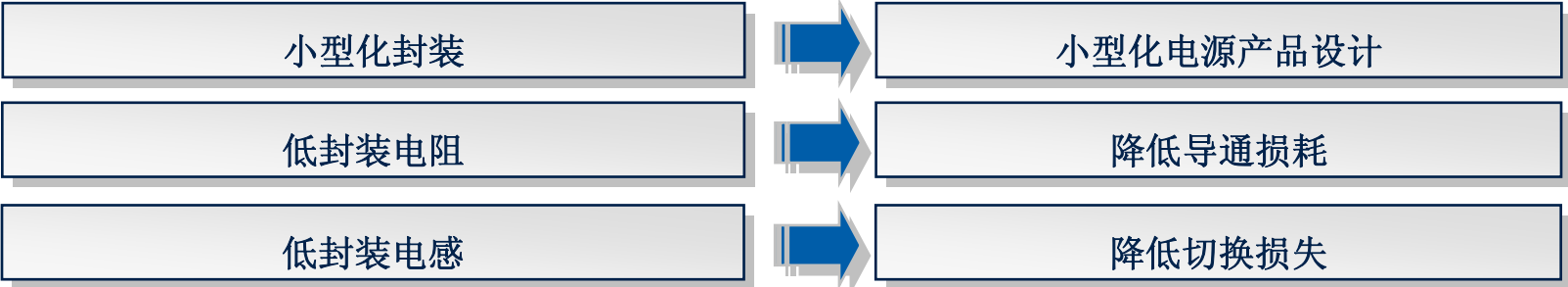


SuperS08封装的特色



特色	
<u>VDS</u>	<u>250V</u>
<u>ID max</u>	<u>100 A</u>
<u>Rpackage</u>	<u>0.2 mW</u>
<u>Rthjc</u>	<u>1 K/W</u>
<u>Tjmax</u>	<u>150° C</u>

最佳化的封装设计，达到高功率密度系统设计要求



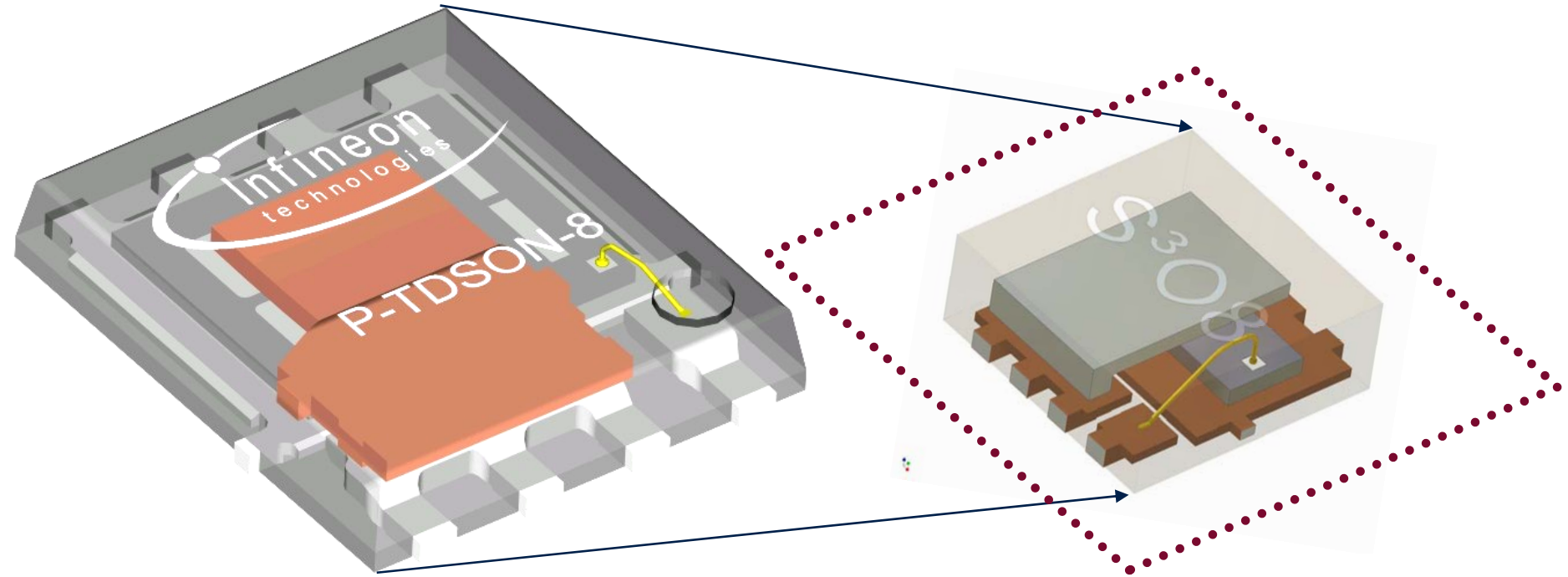
S308封装

为最高功率密度之封装

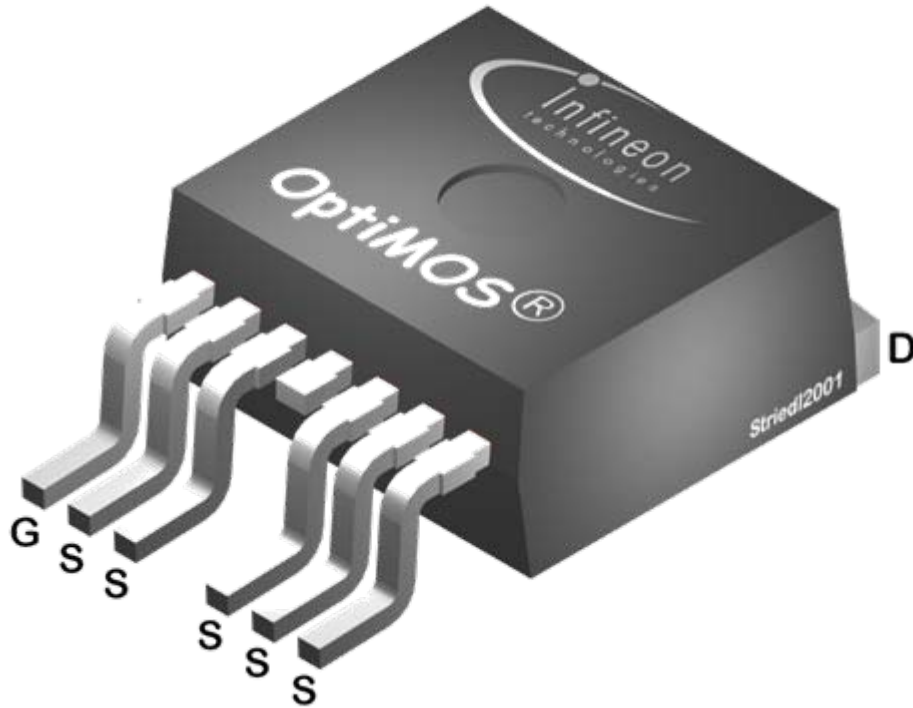
SuperS08



S308 (11mm²)



D2-Pak 7Pin 封装技术



封装大小
标准D2-Pak

封装技术电气特色
达到180A的电流导通能力

可靠度
极低的热阻very low Rth
极大的源极连接，不易在内部
造成热点

世界最低导通电阻之功率晶体管!!
IPB009N03L G
0.95mOhmmax; 30V

S308封装技术

Cu-clip

内部采引线夹 (clip) 接线方式
极低的封装电阻
极低的封装电感
大电流导通能力







Au-wire
(gate)

Die

Leadframe

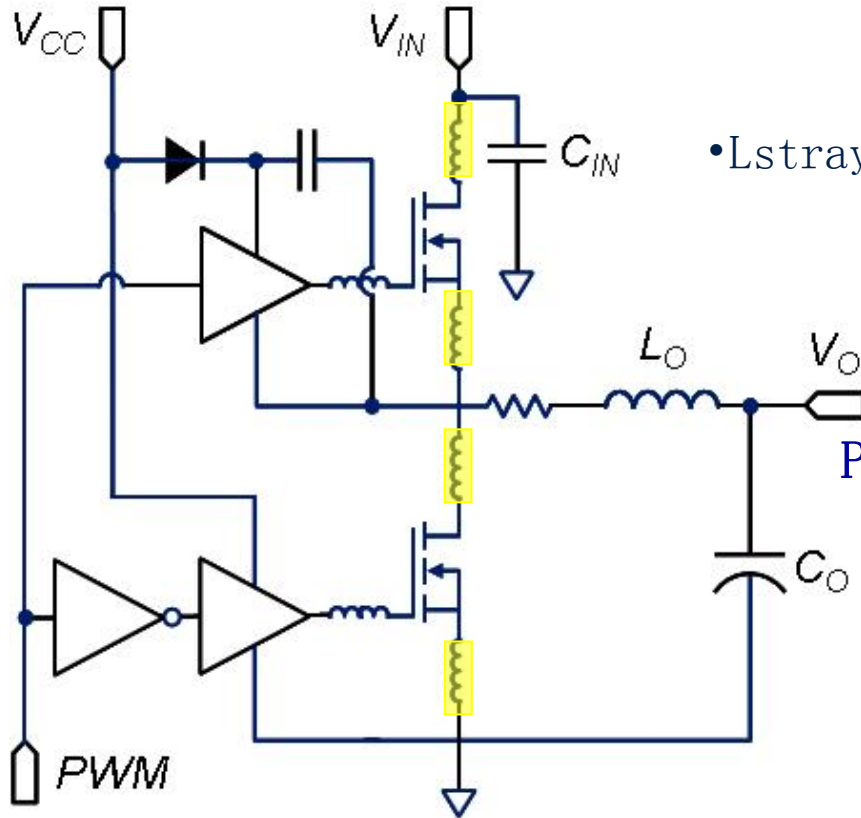


裸晶粒下之各式封装参数比较表

	封装电感	封装电阻	上层冷却能力	下层冷却能力	并联使用难易度
S08 	1.5nH	2.3m Ω	否	否	普通
SS08 	0.6nH	0.2m Ω	受限制	是	普通
S308 	0.5nH	0.3m Ω	受限制	是	易
CanPAK SQ 	0.3nH	0.2m Ω	是	是	易
CanPAK MX 	0.3nH	0.2m Ω	是	是	易
DPAK 	3.8nH	0.5m Ω	否	是	普通

- 封装寄生电感影响切换速度及寄生电感存贮之能量
- 封装寄生电值影响等效导通电阻

寄生电感的影响



• L_{stray} : 回路之总寄生电感值，来自封装及及线路

寄生电感之存贮能量为

$$P = f_{sw} * E_{stray} =$$

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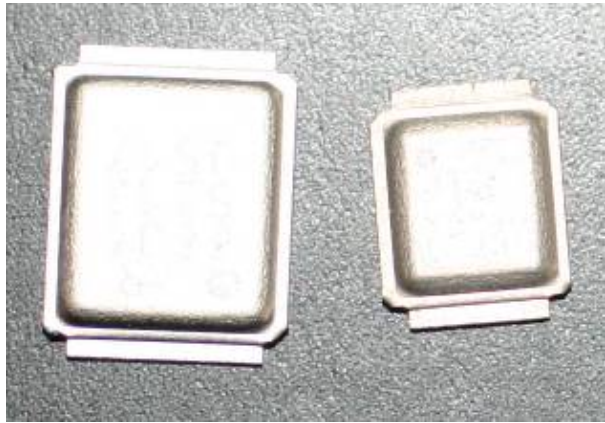
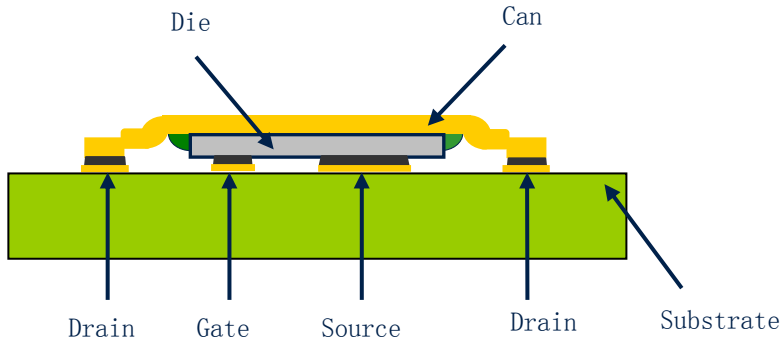
英飞凌之首颗双层散热封装功率晶体管- CanPAK

- ❑ 产品特点
- ❑ 符合国际规范要求
- ❑ 高效能上层冷却能力(低热阻 $R_{th}(J-C)$)
- ❑ 无引线封装
- ❑ 极低之封装电感值
- ❑ 极低之封装电阻值
- ❑ 极佳的优质化系数表现

- ❑ 产品优势
- ❑ 易于散热
- ❑ 提高系统效率
- ❑ 功率晶体管的高速切换及高频操作
- ❑ 易于并联使用



CanPak概述



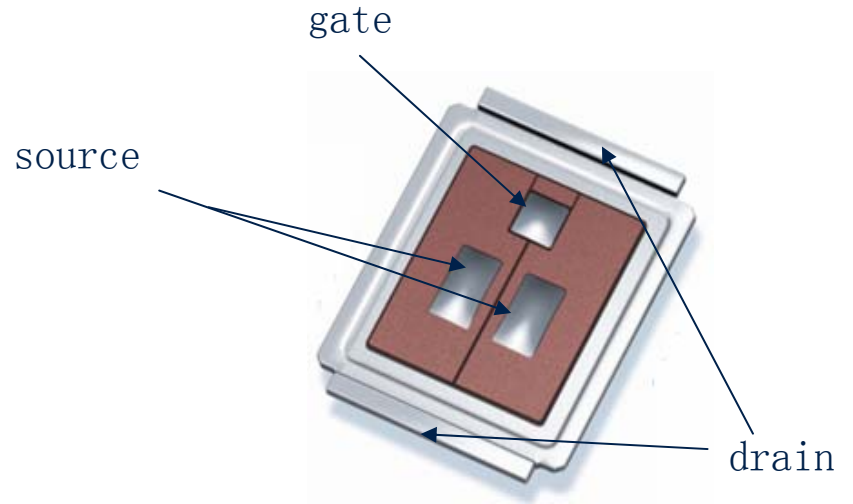
Can M

6.3 x 4.9 mm²

Can S

4.9 x 3.6 mm²

- 高度: 0.7 mm
- 包装面积 M: 31.0 mm²
- 包装面积

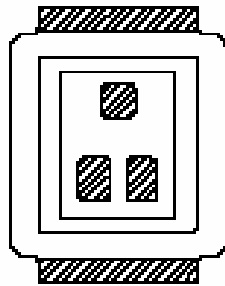


• 无引线封装

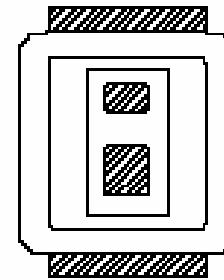
Small Can S / Medium Can M – Outlines

S series

ST-outline

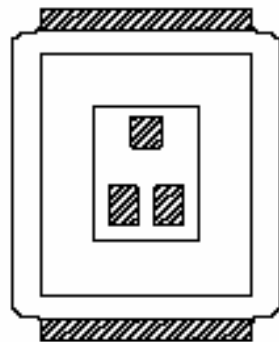


SQ-outline

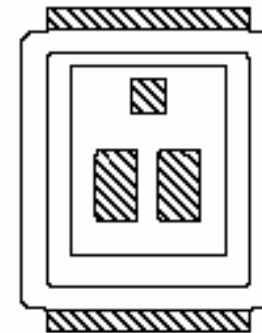


M series

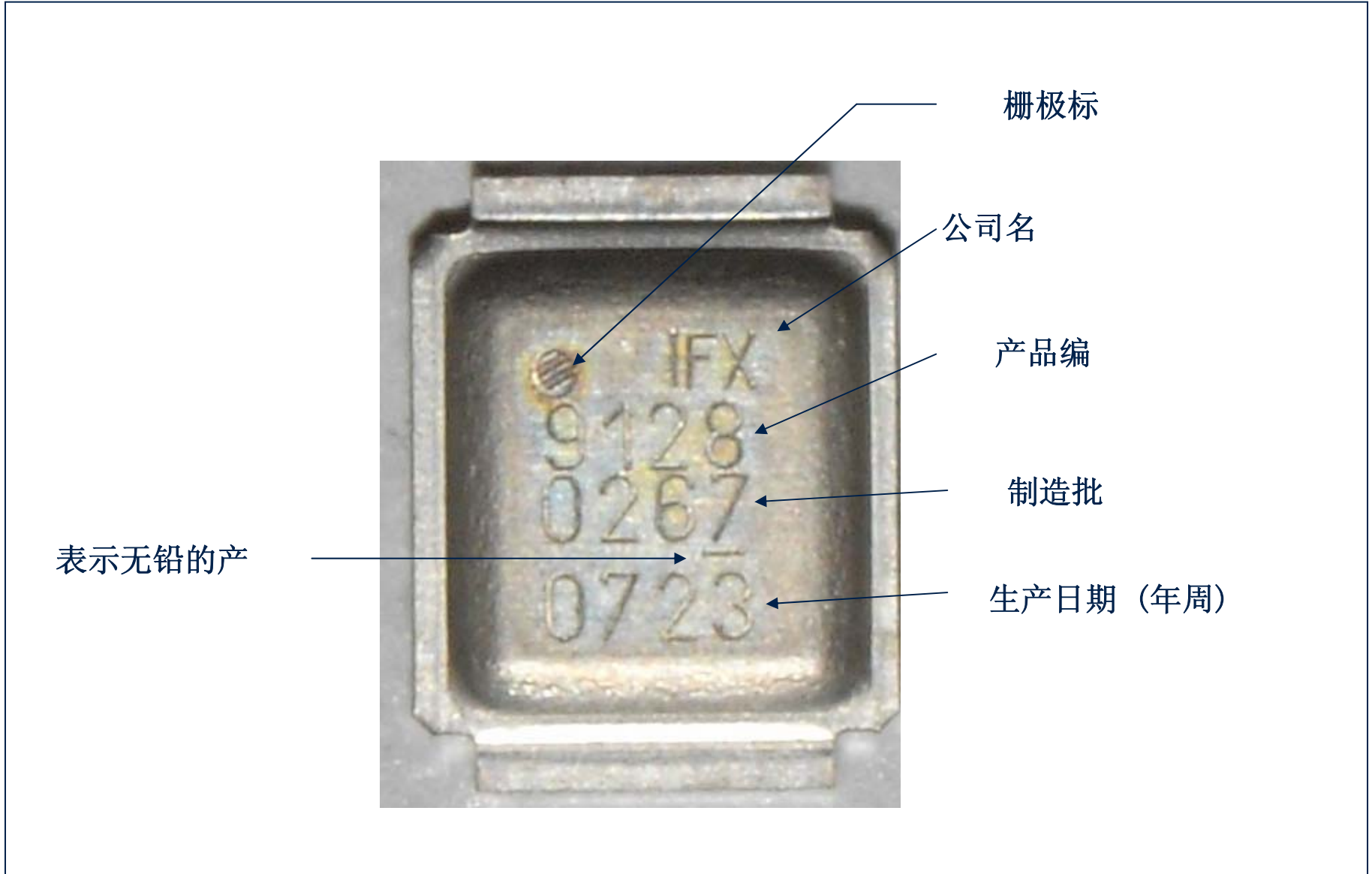
MP-outline



MX-outline



标记



热阻比较表 – CanPAK MX vs SS08

SS08

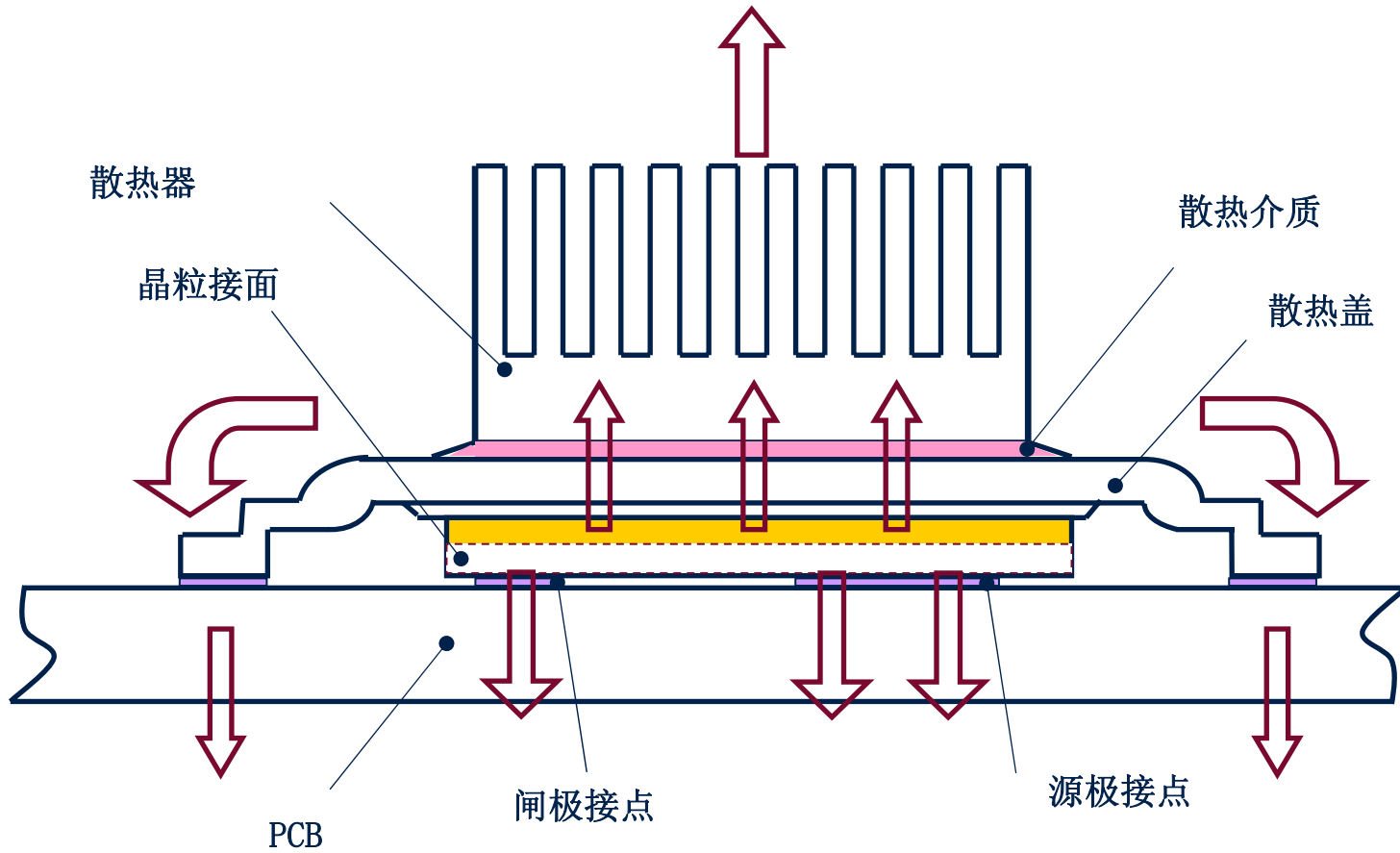
30V SS08 Outline	
Rth(散热介质) [°C/W]	8
Rth(J-C, top) [°C/W]	14
Rth(散热器) [°C/W]	15
总热阻 Rth(top) [°C/W]	37

CanPAK

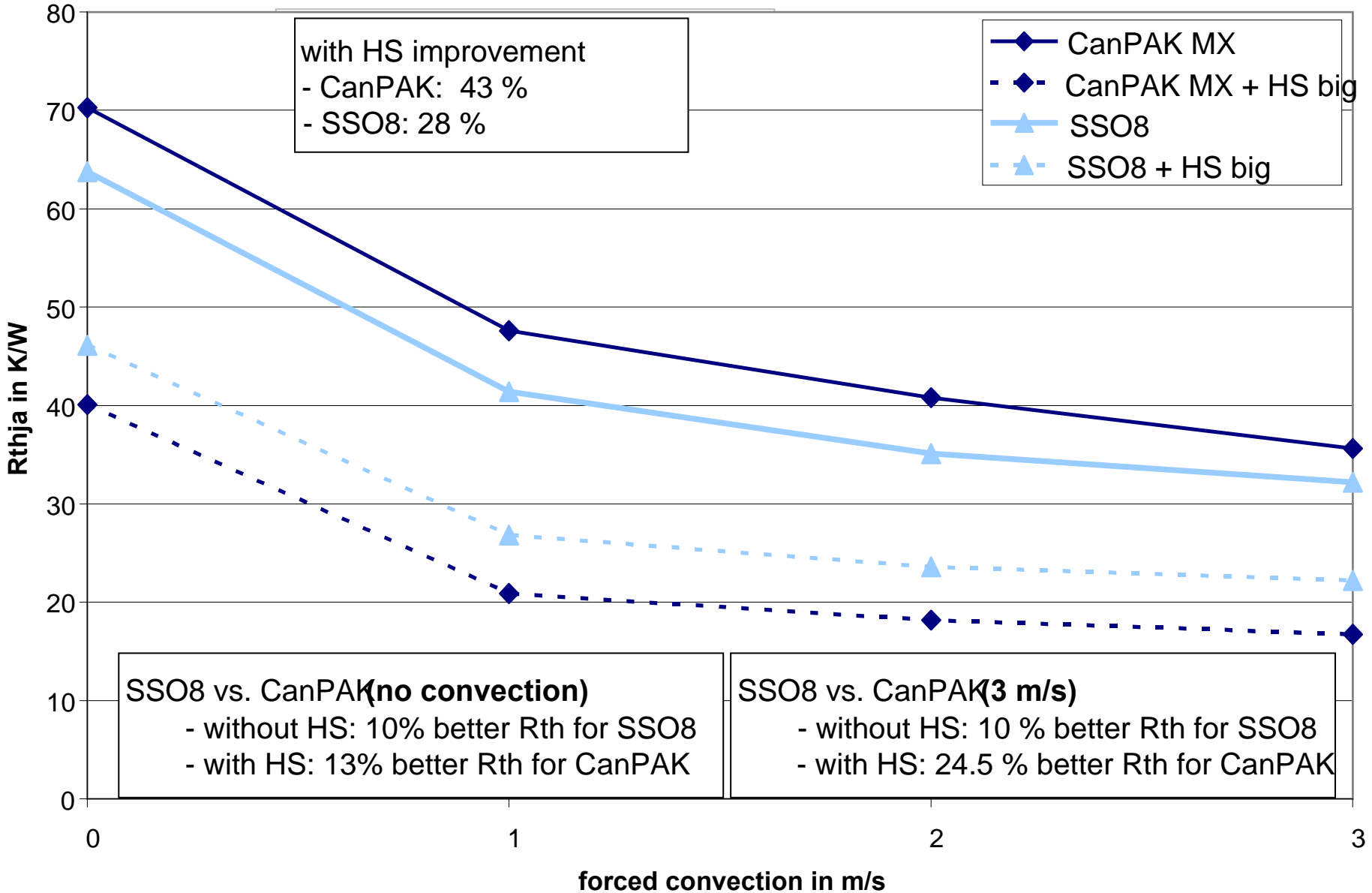
30V CanPAK Outline	
Rth(散热介质) [°C/W]	8
Rth(J-C, top) [°C/W]	2
Rth(散热器) [°C/W]	15
总热阻 Rth(top) [°C/W]	25

CanPAK之总热阻表现约较SS08低50%

热流示意图



热阻量测



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OptiMOS™ Naming System

Package Type

BSB for CanPAK™ (M Can)
 BSC for SuperSO8
 BSF for CanPAK™ (S Can)
 BSO for SO-8
 BSZ for S308

IPA for FullPAK
 IPB for D²PAK
 IPC for Chip Product
 IPD for DPAK
 IPF for Reverse DPAK
 IPI for I²PAK
 IPP for TO-220
 IPS for IPAK
 Short Leads

N for N-channel
P for P-channel
C for Complementary

Level

N for Normal Level	(NL)	to be used from VGS[V]
M for Logic Level 5V opt.	(LL)	10.0
L for Logic Level	(ELL)	4.5
K for Super Logic Level	(SLL)	4.5
J for Ultra Logic Level	(ULL)	2.5
		1.8

Technology Generation
 3 for OptiMOS™3

Green Product



R_{on} in mOhm , multiplied by 10,

if last digit is not defined, substitution by C,
 e.g. 07C = 7mOhm class.
 for chip products chip area in mm²
 multiplied by 10

Package Options

SO-8 / SuperSO8 / S308

S for single Chip (only valid for)
 D for dual Chip (only valid for SO-8 / SuperSO8 / S308)

CanPAK

Q for SQ or MQ footprint
 X for SX or MX footprint
 T for ST or MT footprint
 P for MP footprint

D²PAK

X for xtra drain lead

Breakdown voltage divided by 10



E = extended, +5V, e.g. E2=25V

Features

F for fast switching
 R for integrated gate resistor
 E for ESD protection
 C for clean switching
 e.g. IPD04xP03LE G

OptiMOS™ 20V Super Logic Level (SLL)







	SO-8	SuperSO8
		
1.9 mΩ		BSC019N02KS G
2.6 mΩ		BSC026N02KS G
4.6 mΩ		BSC046N02KS G
32 mΩ	BSO330N02K G	

More 20V SLL products in small signal packages available

NEW

OptiMOS™ 25V: Performance optimized for Server, Datacom, Telecom Applications



	SuperS08	S308		CanPAK™ M	CanPAK™ S
< 1.0 mΩ			< 1.0 mΩ		
1.0 - 1.5 mΩ	BSC010NE2LS		1.0 - 1.5 mΩ	BSB012NE2LX BSB013NE2LXI	
1.6 - 2.0 mΩ	BSC018NE2LS	BSZ018NE2LS	1.6 - 2.0 mΩ		
2.1 - 2.5 mΩ	BSC024NE2LS		2.1 - 2.5 mΩ		
3.0 - 4.0 mΩ	BSC032NE2LS	BSZ036NE2LS	4.1 - 4.5 mΩ		BSF030NE2LQ
4.1 - 4.5 mΩ			4.6 - 5.0 mΩ		
4.6 - 5.0 mΩ	BSC050NE2LS		5.1 - 5.5 mΩ		
5.1 - 5.5 mΩ			5.6 - 6.0 mΩ		
5.6 - 6.0 mΩ		BSZ060NE2LS			



OptiMOS™ 30V: Released for Industrial Applications

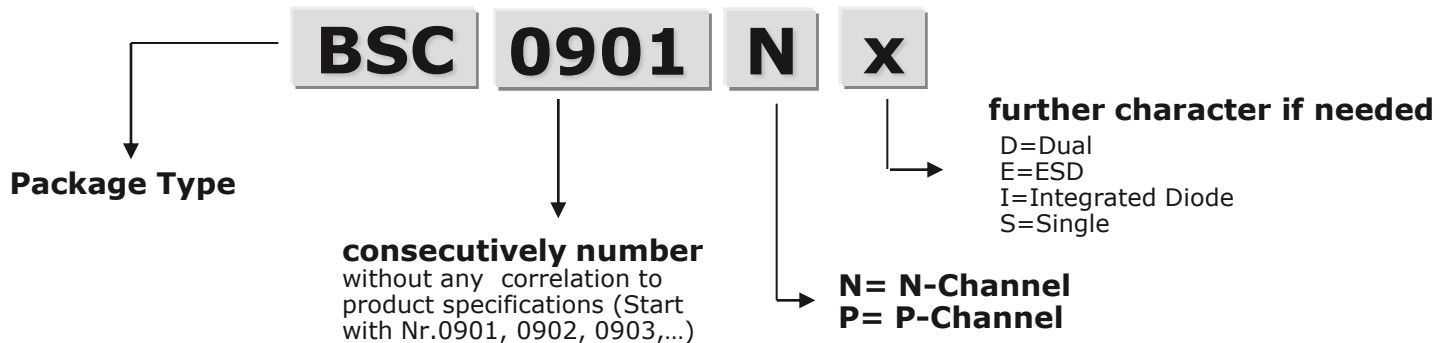
Performance optimized for Notebook, VGA Applications



	SuperSO8	S308	S308 - dual (Power Stage 3x3)
1.0 - 1.5 mΩ	BSC011N03LS		
1.6 - 2.0 mΩ	BSC0901NS	BSZ019N03LS	
2.1 - 2.5 mΩ	BSC0901NSI		
2.6 - 3.0 mΩ	BSC0902NS	BSZ0901NSI	
3.1 - 3.5 mΩ	BSC0902NSI	BSZ0902NS	
3.6 - 4.0 mΩ	BSC0904NSI	BSZ0902NSI	
4.1 - 4.5 mΩ			
5.1 - 5.5 mΩ	BSC0906NS		
6.1 - 6.5 mΩ	BSC052N03LS	BSZ0904NSI	
7.0 - 8.0 mΩ	BSC0908NS		
> 9.0 mΩ	BSC0909NS	BSZ065N03LS	
20 mΩ		BSZ0905NS	
		BSZ0909NS	
		BSZ0920NS	

7+9 mΩ	BSZ0907ND
9+19 mΩ	BSZ0908ND

Grey: Upcoming products



OptiMOS™ 30V Logic Level



<1.6 mΩ
1.6-2 mΩ
2-3 mΩ
3-4 mΩ
4 mΩ
5 - 6 mΩ
6 - 7 mΩ
7-8 mΩ
8-10 mΩ
10-13 mΩ
13-15 mΩ

IPP034N03L G
IPP042N03L G
IPP055N03L G
IPP065N03L G
IPP080N03L G
IPP096N03L G
IPP114N03L G
IPP147N03L G

IPB034N03L G
IPB042N03L G
IPB055N03L G
IPB065N03L G
IPB080N03L G
IPB096N03L G
IPB114N03L G
IPB147N03L G

IPB009N03L G

IPS031N03L G
IPS040N03L G
IPS050N03L G
IPS060N03L G
IPS075N03L G
IPS090N03L G
IPS105N03L G
IPS135N03L G

IPD031N03L G
IPD040N03L G
IPD050N03L G
IPD060N03L G
IPD075N03L G
IPD090N03L G
IPD105N03L G
IPD135N03L G

BSC014N03LS G
BSC016N03LS G
BSC020N03LS G
BSC025N03LS G
BSC030N03LS G
BSC034N03LS G
BSC042N03LS G
BSC050N03LS G
BSC057N03LS G
BSC080N03LS G
BSC090N03LS G
BSC100N03LS G
BSC120N03LS G

BSZ035N03LS G
BSZ050N03LS G
BSZ058N03LS G
BSZ088N03LS G
BSZ100N03LS G
BSZ130N03LS G

2 x 7,2 mΩ
2 x 15mΩ

BSC072N03LD G
BSC150N03LD G






1-3mΩ
3-6 mΩ

BSB012N03LX3 G
BSB017N03LX3 G

BSF024N03LT3 G
BSF050N03LQ3 G



OptiMOS™ 30V Enhanced Logic Level (M-Series)



	S-08	SuperS08	S308
			
1 - 2 mΩ		BSC014N03MS G BSC016N03MS G	
2 - 4 mΩ	BSO033N03MS G BSO040N03MS G	BSC020N03MS G BSC025N03MS G BSC030N03MS G	BSZ035N03MS G
4 - 6 mΩ	BSO051N03MS G	BSC042N03MS G BSC050N03MS G BSC057N03MS G	BSZ050N03MS G BSZ058N03MS G
6 - 7 mΩ	BSO065N03MS G		
8 - 9 mΩ	BSO083N03MS G	BSC090N03MS G BSC080N03MS G	BSZ088N03MS G
10 - 13 mΩ	BSO110N03MS G BSO130N03MS G	BSC100N03MS G BSC120N03MS G	BSZ100N03MS G BSZ130N03MS G
22 mΩ	BSO220N03MS G		
2 x 15 mΩ	BSO150N03MD G		
2 x 22 mΩ	BSO220N03MD G		








OptiMOS™ 40V Logic Level



	TO-220 	TO-263 (D ² PAK) 	TO-263 7Pin (D ² PAK 7Pin) 	TO-252 (DPAK) 	SuperSO8 	S308 	CanPAK™ M 
1 - 2 mΩ		IPB015N04L G	IPB011N04L G		BSC016N04LS G BSC018N04LS G		BSB014N04LX3 G
2 mΩ							
2 - 3 mΩ		IPB022N04L G			BSC027N04LS G		
3 - 4 mΩ	IPP039N04L G	IPB039N04L G		IPD036N04L G	BSC035N04LS G BSC050N04LS G BSC059N04LS G	BSZ040N04LS G	
5- 6 mΩ							
7 - 8 mΩ		IPB075N04L G			BSC093N04LS G	BSZ097N04LS G	
9 - 10 mΩ		IPB093N04L G		IPD088N04L G IPD105N04L G IPD160N04L G			
10 - 11 mΩ							
13 - 17 mΩ							








OptiMOS™ 40V Normal Level



	TO-220 	TO-263 (D ² PAK) 	TO-263 7Pin (D ² PAK 7Pin) 	TO-252 (DPAK) 	SuperS08 	S308 	CanPAK™ M 
1 - 2 mΩ	IPP015N04N G	IPB015N04N G	IPB011N04N G		BSC017N04NS G		BSB015N04NX3 G
2 - 3 mΩ	IPP023N04N G	IPB023N04N G	IPB020N04N G		BSC019N04NS G		
3 - 4 mΩ	IPP041N04N G	IPB041N04N G		IPD038N04N G	BSC030N04NS G	BSZ042N04NS G	
4 - 7 mΩ	IPP048N04N G IPP065N04N G	IPB052N04N G			BSC054N04NS G		
10 - 11 mΩ						BSZ105N04NS G	
13 - 18 mΩ				IPD170N04N G		BSZ165N04NS G	






OptiMOS™ 60V Logic Level



	TO-220 	TO-262 (I ² PAK) 	TO-263 (D ² PAK) 	TO-263 7Pin (D ² PAK 7Pin) 	TO-252 (DPAK) 	SuperS08 	S308 
1 mΩ			IPB019N06L3 G	IPB016N06L3 G		BSC028N06LS3 G	
2-3 mΩ							
3-4 mΩ	IPP037N06L3 G	IPI037N06L3 G	IPB034N06L3 G		IPD031N06L3 G IPD035N06L3 G		
4-5 mΩ			IPB048N06L G IPB049N06L3 G		IPD048N06L3 G		
5-6 mΩ	IPP052N06L3 G						
6-7 mΩ	IPP065N06L G					BSC067N06LS3 G	BSZ067N06LS3 G
7-8 mΩ	IPP085N06L G						
8-10 mΩ	IPP084N06L3 G		IPB081N06L3 G		IPD079N06L3 G	BSC100N06LS3 G	BSZ100N06LS3 G
10-13 mΩ							
20-30 mΩ	IPP230N06L3 G		IPB230N06L3 G		IPD127N06L G IPD220N06L3 G IPD350N06L G IPD640N06L G		
35 mΩ							
64 mΩ							

OptiMOS™ 60V Normal Level







	TO-220 	TO-262 (I ² PAK) 	TO-220 FullPAK 	TO-263 (D ² PAK) 	TO-263 7Pin (D ² PAK 7Pin) 
1 mΩ					IPB017N06N3 G
2-3 mΩ	IPP024N06N3 G	IPI024N06N3 G		IPB021N06N3 G IPB029N06N3 G	IPB023N06N3 G
3-4 mΩ	IPP032N06N3 G	IPI032N06N3 G	IPA032N06N3 G	IPB037N06N3 G	IPB034N06N3 G
4 mΩ	IPP040N06N3 G	IPI040N06N3 G			
5-7 mΩ	IPP057N06N3 G		IPA057N06N3 G	IPB050N06N G IPB054N06N3 G	
8-10 mΩ	IPP093N06N3 G		IPA093N06N3 G	IPB090N06N3 G	
10-13 mΩ	IPP120N06N G				
20-30 mΩ	IPP260N06N3 G			IPB260N06N3 G	

	TO-252 (DPAK) 	SuperSO8 	S308 	CanPAK™ M 	CanPAK™ S 
1-3 mΩ				BSB028N06NN3 G	
3-4 mΩ	IPD034N06N3 G IPD038N06N3 G	BSC031N06NS3 G			
4 mΩ					
5-6 mΩ	IPD053N06N3 G				
7-8 mΩ		BSC076N06NS3 G	BSZ076N06NS3 G		BSF077N06NT3 G
8-10 mΩ	IPD088N06N3 G		BSZ110N06NS3 G		
10-14 mΩ	IPD144N06N G	BSC110N06NS3 G			
20-30 mΩ	IPD230N06N G IPD250N06N3 G				
40 mΩ	IPD400N06N G				
80 mΩ	IPD800N06N G				

Grey: Upcoming products, will be released in April 2011

OptiMOS™ 75V Normal Level



	TO-220	TO-263 (D2PAK)	TO-262 (I2PAK)	SuperS08
				
2-4 mΩ	IPP023NE7N3 G IPP034NE7N3 G	IPB031NE7N3 G IPB020NE7N3 G	IPI023NE7N3 G IPI034NE7N3 G	BSC042NE7NS3 G
4-6 mΩ	IPP052NE7N3 G	IPB049NE7N3 G	IPI052NE7N3 G	
6-12 mΩ	IPP062NE7N3 G			

OptiMOS™ 80V



- 2.2 mΩ**
- 2-3 mΩ**
- 3-4 mΩ**
- 4-6 mΩ**
- 6-7 mΩ**
- 8-11 mΩ**
- 11-20 mΩ**

IPP028N08N3 G	IPI028N08N3 G		IPA028N08N3 G	IPB025N08N3 G	IPB019N08N3 G	
IPP037N08N3 G	IPI037N08N3 G		IPA037N08N3 G	IPB035N08N3 G	IPB030N08N3 G	
IPP057N08N3 G	IPI057N08N3 G		IPA057N08N3 G	IPB054N08N3 G		IPD053N08N3 G
IPP070N08N3 G	IPI070N08N3 G			IPB067N08N3 G		
IPP100N08N3 G	IPI100N08N3 G		IPA100N08N3 G	IPB097N08N3 G		IPD096N08N3 G
IPP139N08N3 G	IPI139N08N3 G	IPU135N08N3 G		IPB136N08N3 G		IPD135N08N3 G



- 2.2 mΩ**
- 2-3 mΩ**
- 3-4 mΩ**
- 4-6 mΩ**
- 6-7 mΩ**
- 8-11 mΩ**
- 11-20 mΩ**
- 30-40 mΩ**

BSC047N08NS3 G		BSB044N08NN3 G
BSC057N08NS3 G		
BSC123N08NS3 G	BSZ123N08NS3 G	
BSC340N08NS3 G	BSZ340N08NS3 G	

Grey: Upcoming products, will be released in April 2011

OptiMOS™ 100V Logic Level



	TO-220 	TO-251SL (IPAK SL) 	SuperSO8 	Replacement for Super SO8
5 mΩ	IPP05CN10L G			
6 mΩ	IPP06CN10L G			
8 - 9mΩ	IPP08CN10L G			
10 - 11 mΩ				
12 - 13 mΩ	IPP12CN10L G	IPS12CN10L G		
15 - 16 mΩ	IPP16CN10L G			
20 - 21 mΩ			BSC082N10LS G²	BSC070N10NS3 G
26 - 27 mΩ			BSC105N10LSF G²	BSC109N10NS3 G
			BSC123N10LS G²	BSC109N10NS3 G
			BSC159N10LSF G²	BSC160N10NS3 G
			BSC205N10LS G²	BSC160N10NS3 G
			BSC265N10LSF G²	BSC160N10NS3 G

2) Product is „not for new design“ and will be discontinued soon

OptiMOS™ 100V Normal Level (6V Gate rating)



2-3 mΩ	IPP030N10N3 G	IPA030N10N3 G	IPI030N10N3 G	IPB027N10N3 G	IPB025N10N3 G IPB039N10N3 G	
3-4 mΩ						
4-6 mΩ	IPP045N10N3 G	IPA045N10N3 G	IPI045N10N3 G	IPB042N10N3 G		
6-8 mΩ	IPP072N10N3 G		IPI072N10N3 G			
8-12 mΩ	IPP086N10N3 G	IPA086N10N3 G	IPI086N10N3 G	IPB083N10N3 G	IPD068N10N3 G	
12-18 mΩ	IPP126N10N3 G	IPA126N10N3 G	IPI126N10N3 G	IPB123N10N3 G	IPD082N10N3 G	IPS118N10N G*
18-20 mΩ	IPP180N10N3 G	IPA180N10N3 G	IPI180N10N3 G		IPD122N10N3 G	
20-26 mΩ	IPP26CN10N G^{2*}		IPI26CN10N G^{2*}	IPB26CN10N G^{2*}	IPD180N10N3 G	
26-35 mΩ			IPI35CN10N G^{2*}	IPB34CN10N G^{2*}	IPD25CN10N G*	
35-50 mΩ	IPP50CN10N G^{2*}		IPI50CN10N G^{2*}	IPB50CN10N G^{2*}	IPD33CN10N G*	
70-80 mΩ	IPP80CN10N G^{2*}		IPI80CN10N G^{2*}		IPD78CN10N G*	

	SuperSO8	S308	CanPAK™ M	CanPAK™ S
3-5 mΩ				
5-7 mΩ	BSC060N10NS3 G		BSB056N10NN3 G	
7-10 mΩ	BSC070N10NS3 G			
10-11 mΩ	BSC109N10NS3 G			
11-15 mΩ				BSF134N10NJ3 G
16-19 mΩ	BSC160N10NS3 G	BSZ160N10NS3 G		
26-50 mΩ	BSC440N10NS3 G	BSZ440N10NS3 G		
2 x 75 mΩ	BSC750N10ND G			







Grey: Upcoming products, will be released in April(CanPAK)/August(SuperSO8) 2011



* Not 6V rated

2) Product is „not for new design“ and will be discontinued soon

OptiMOS™ 120V












	TO-220 	TO-262 (I ² PAK) 	TO-263 (D ² PAK) 	TO-263 7Pin (D ² PAK 7Pin) 	TO-252 (DPAK) 	TO-251 SL (IPAK SL) 
3-4 mΩ	IPP041N12N3 G	IPI041N12N3 G	IPB038N12N3 G	IPB036N12N3 G		
4-5 mΩ	IPP048N12N3 G	IPI048N12N3 G				
7-8 mΩ						
8-10 mΩ	IPP076N12N3 G	IPI076N12N3 G				
10-13 mΩ	IPP114N12N3 G				IPD110N12N3 G	IPS110N12N3 G
13-20 mΩ	IPP147N12N3 G	IPI147N12N3 G	IPB144N12N3 G			
20-25 mΩ						

	SuperS08 	S308 
3-4 mΩ		
4-5 mΩ		
7-8 mΩ	BSC077N12NS3 G	
8-10 mΩ		
10-13 mΩ		
13-20 mΩ	BSC190N12NS3 G	
20-25 mΩ	BSC240N12NS3 G	BSZ240N12NS3 G

OptiMOS™ 150V (8V Gate rating)



	TO-220 	TO-220 (Full Pak) 	TO-262 (I ² PAK) 	TO-263 (D ² PAK) 	TO-263 Pin (D ² PAK 7Pin) 	TO-252 (DPAK) 
6-7 mΩ					IPB065N15N3 G	
7-11 mΩ	IPP075N15N3 G IPP111N15N3 G	IPA075N15N3 G IPA105N15N3 G	IPI075N15N3 G IPI111N15N3 G	IPB072N15N3 G IPB108N15N3 G		
19-30 mΩ	IPP200N15N3 G		IPI200N15N3 G	IPB200N15N3 G		IPD200N15N3 G
50-60 mΩ	IPP530N15N3 G		IPI530N15N3 G	IPB530N15N3 G		IPD530N15N3 G

	SuperSO8 	S308 	CanPAK™ M 
6-7 mΩ			BSB150N15NZ3 G
7-15 mΩ			BSB280N15NZ3 G
19-30 mΩ	BSC190N15NS3 G		
30-50 mΩ	BSC360N15NS3 G		
50-60 mΩ	BSC520N15NS3 G	BSZ520N15NS3 G	
80-90 mΩ		BSZ900N15NS3 G	

Grey: Upcoming products, will be released in April 2011

OptiMOS™ 200V









	TO-220	TO-262 (I ² PAK)	TO-263 (D ² PAK)	TO-252 (DPAK)	SuperS08	S308
~10mΩ	IPP110N20N3 G IPP110N20NA ³	IPI110N20N3 G	IPB107N20N3 G IPB107N20NA ³			
30-40mΩ	IPP320N20N3 G	IPI320N20N3 G	IPB320N20N3 G	IPD320N20N3 G	BSC320N20NS3 G	BSZ900N20NS3 G
90mΩ					BSC900N20NS3 G	BSZ12DN20NS3 G
120mΩ					BSC12DN20NS3 G	BSZ22DN20NS3 G
220mΩ					BSC22DN20NS3 G	

3) part qualified for Automotive
newly released within this update

OptiMOS™ 250V



	TO-220 	TO-262 (I²PAK) 	TO-263 (D²PAK) 	TO-252 (DPAK) 	SuperS08 	S308 
~30mΩ	IPP200N25N3 G	IPI200N25N3 G	IPB200N25N3 G			
~80mΩ	IPP600N25N3 G	IPI600N25N3 G	IPB600N25N3 G	IPD600N25N3 G	BSC600N25NS3 G	
~100-300mΩ					BSC16DN25NS3 G	BSZ16DN25NS3 G
~400-500mΩ						BSZ42DN25NS3 G

低电压功率晶体管结构

晶粒技术发展

封装技术发展

双层冷却封装之功率晶体管 – CanPAK

英飞凌之低电压功率晶体管

总结

总结

- 低电压功率晶体管的晶粒技术发展方向在于能够在单位面积之中发展具有更低优质化系数FOM的晶粒
- 低电压功率晶体管的封装技术发展方向在于有效减少封装的热阻 ($R_{th, J-C}$).
- 英飞凌科技公司所提供之CanPAK产品乃是结合高效能晶粒OptiMOS技术及高效能封装之产品
- 英飞凌科技公司提供的OptiMOS系列低电压功率晶体管产品乃是目前世界上具有最低优质化系数之高效能产品



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